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Anthracene derivative based multifunctional liquid crystal materials for optoelectronic devices†

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Device integration is among the current research trends in the area of organic electronics and the development of multifunctional materials is crucial to accelerate the progress of integrated devices, such as organic light-emitting transistors (OLET), organic field-effect optical waveguides (OFEW) and organic electrofluorochromic (OEFC) devices. Herein, two multifunctional materials with different side chains, 2-(4-octyloxyphenyl)anthracene (**AntPh-OC8**) and 2-(4-octylphenyl)anthracene (**AntPh-C8**), based on the concept of combining liquid crystal (LC) materials featuring facile processability, highly ordered alignment and effective charge transport and an anthracene conjugated core with strong fluorescence, are designed and successfully synthesized. The photoluminescence quantum yield (PLQY) of **AntPh-OC8** and **AntPh-C8** is determined to be 40.9% and 37.6%, respectively, which approaches nearly 2-fold that of 2-phenylanthracene (**AntPh**). Organic light-emitting diodes (OLED) based on **AntPh-OC8** confirmed its solid-state blue emission with a current efficiency (CE) of 1.82 cd A^{-1}, whereas the corresponding organic field-effect transistors (OFET) demonstrated the highest hole mobility of up to 2.59 cm^2 V^{-1} s^{-1}. Organic phototransistors (OPT) comprising **AntPh-OC8** and **AntPh-C8** revealed efficient photoresponsive characteristics of these newly developed materials. These demonstrations indicate the widespread potential of our newly developed materials for applications in multifunctional integrated devices. Moreover, these results indicate the encouraging role of side-chain engineering in the improvement of charge transport and fluorescence characteristics of anthracene derivatives.

Introduction

Benefitting from the advantages of flexibility, tunability, low-cost and facile solution processability, organic semiconductors (OSCs) have attracted wide attention of the research community.[1–3] Consequently, organic electronics has advanced quickly in the past few decades. Organic field-effect transistors (OFETs) are regarded as the basic building blocks for the foundation of organic electronics due to their extensive applications in integrated circuits, displays, photodetectors, radio frequency identification (RFID) and other optoelectronic devices.[4–6] For example, an organic phototransistor (OPT), in which the source–drain current can be amplified under incident light, is a type of photodetector which exhibits comparable photo-responsivity to that of its inorganic counterparts ($\sim$300 A W^{-1}).[7,8] Meanwhile, taking advantage of the intrinsic properties of dual-functional or multifunctional materials,

integrated devices can be fabricated to achieve various applications in a single device, such as organic light-emitting transistors (OLETs),[9,10] organic field-effect waveguides (OFEWs)[11,12] and organic electrofluorochromic (OEFC) devices,[13,14] which opens up opportunities for device integration in a more straightforward way. Among them, OLETs, being fabricated *via* integrating an emitting pixel along with its driving transistor, not only exhibit potential for utilization in the display industry, but also can serve as a platform for the realization of electrically pumped organic lasers. Therefore, in order to extend the applications of OSCs and simplify the device structure, designing molecules with versatile properties, which could offer processability and the potential of being applied in electronic or optoelectronic devices, is crucial.

Aromatic hydrocarbon anthracene is a well-known candidate for organic optoelectronics.[15–17] Since the invention of the first electroluminescent device based on an anthracene single crystal in 1967,[18] anthracene, a less conjugated acene compared with tetracene and pentacene, has been widely utilized in the realm of organic light-emitting diodes (OLEDs) due to its desirable fluorescence properties and air stability. Moreover, the dense packing and strong intermolecular interactions of rigid aromatic anthracene lead to efficient charge transport; as a result, many anthracene derivatives with high mobility have been designed

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† Electronic supplementary information (ESI) available. See DOI: 10.1039/d0qm00038h

and synthesized for applications in OFETs.[19–22] Recently, combining strong fluorescence with efficient charge transport, several benchmark anthracene derivatives have been reported. A. Dadvand *et al.* demonstrated blue solid-state emission and p-channel mobility in an anthracene derivative, HPVAnt, and reasoned that suppression of singlet fission contributed to the improved PLQY of 70% in their synthesized compound compared with its tetracene counterpart.[23] With a J-aggregation mode and extended conjugation, 2,6-position substituted dNaAnt and DPA exhibit strong fluorescence and high mobility.[24,25] Further optimization of the device geometry can lead to them fully realizing their potential as active layers in OLETs with external quantum efficiency values approaching 1.75% and 1.65%.[26] It is worth mentioning that most of the encouraging results are achieved using highly-ordered and defect-free single crystals, in which charge carrier trapping and fluorescence quenching are effectively avoided.[27] However, single crystals generally require complicated fabrication processes and offer inferior flexibility.

In contrast to the single-crystal device fabrication by complicated, expensive and time-consuming processes, highly ordered crystalline thin films for OFETs can be prepared from liquid-crystal states through simple techniques, such as thermal annealing or substrate heating at specific temperatures.[28,29] Moreover, OFETs based on liquid crystals possess high mobility comparable with their single-crystal based counterparts, and the soft nature of liquid-crystal materials fits well with flexible electronics.[30–32] In general, liquid-crystal materials for charge transport are designed as two immiscible parts *via* incorporating π-conjugated cores and non-transporting molecular moieties, such as alkyl chains, alkoxy chains and other groups immiscible with the rigid conjugated moieties, which results in phase segregation of flexible insulating parts and rigid conducting parts.[33] Consequently, liquid crystal materials can easily adopt layer-by-layer structures by π–π stacking and CH–π interactions, which paves the way to efficient charge transport between adjacent molecules. Overall, liquid-crystal materials endowed with well-ordered alignment and acceptable processability are considered as potential candidates for their utilization as active materials in high-performance optoelectronic devices for future flexible electronics.
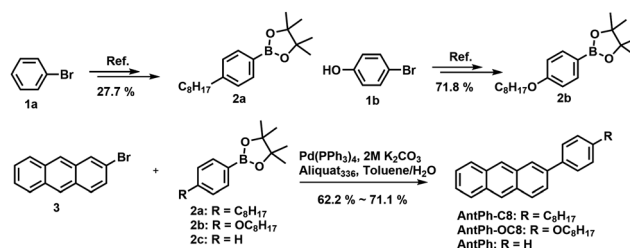
Our group has made some efforts to explore the potential applications of anthracene derivatives. For instance, we realized white OLEDs *via* combining FlAnt with blue emission and 2A with greenish-yellow emission.[34] In addition, OFETs based on mixed FlAnt and 2A exhibited a high mobility of 1.56 cm^2 V^{-1} s^{-1}. Moreover, heteroatom substituted BOPAnt, BSPAnt and BEPAnt were developed to investigate the effect of heteroatoms on the charge mobility and luminescence properties.[35] Also, single crystal OFETs based on BOPAnt were fabricated to study the photo-responsivity[36] and isotropic charge transport.[37] An azo-functionalized anthracene derivative, APDPD, was designed and synthesized for applications in OFETs, which showed reversible isomerization through specific-wavelength photoexcitation and heat treatment.[38] However, the investigation of the charge transport and fluorescence characteristics of anthracene-based liquid crystal materials and the influence of side groups remains unexplored.

Herein, asymmetric liquid crystal materials, AntPh-OC8 and AntPh-C8, are designed and successfully synthesized *via* introducing side chains into the extended conjugated anthracene core, AntPh, in order to develop multifunctional materials for simultaneously realizing efficient charge transport, strong fluorescence and decent photo-detection properties in a single molecule. Importantly, our newly developed materials can easily form decent thin films with desirable molecular orientation and morphology for efficient charge transport owing to their liquid crystal properties, indicating their compatibility with low-cost device fabrication and flexible electronics. In contrast to their parent molecule, AntPh, the side chain substituted derivatives exhibited improved photoluminescence quantum yields (PLQYs). Compared with the average mobility of 0.45 cm^2 V^{-1} s^{-1} for AntPh single crystal OFETs reported elsewhere,[39] we achieved the highest mobility of 2.59 cm^2 V^{-1} s^{-1} in OFETs based on AntPh-OC8. Moreover, the photoresponsive behavior of the two compounds is studied in phototransistors, which showed the highest photo-sensitivity of up to 9.3×10^7 and a responsivity of 515 A W^{-1}. In addition, the OLED containing AntPh-OC8 as the emitter showed pure-blue emission with a CE of 1.82 cd A^{-1}. These demonstrations reveal the potential of AntPh-OC8 and AntPh-C8 for applications in multifunctional devices. Furthermore, our results unveil the beneficial effect of the side chains on the fluorescence efficiency and charge transport characteristics of the resulting materials.

Results and discussion

Synthesis

The synthetic approaches for the liquid crystal materials, 2-(4-octylphenyl)anthracene (AntPh-C8) and 2-(4-octyloxyphenyl)-anthracene (AntPh-OC8), and a non-mesogenic material, 2-phenylanthracene (AntPh), are shown in Scheme 1. Firstly, the key intermediate compounds 2-(4-octylphenyl)-4,4,5,5-tetramethyl-1,3,2-dioxaborolane (2a), 2-(4-octyloxyphenyl)-4,4,5,5-tetramethyl-1,3,2-dioxaborolane (2b) and 2-bromoanthracene (3) were prepared according to previously reported procedures.[38,40–42] Subsequently, the target materials AntPh-C8, AntPh-OC8 and AntPh were synthesized by using 2-bromoanthracene (3) and the corresponding pinathol borate esters (2a, 2b and 2c) *via* a Suzuki–Miyaura coupling reaction. High-purity materials were obtained by gradient vacuum sublimation two to three times. The chemical structures of these new compounds were confirmed by nuclear magnetic resonance (NMR) spectroscopy.

Scheme 1 Synthetic route of AntPh, AntPh-C8 and AntPh-OC8.

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Mater. Chem. Front., 2020, **4**, 3546–3555 | 3547

Thermal and liquid crystal properties

To investigate the thermal and liquid crystal properties of **AntPh-C8**, **AntPh-OC8** and **AntPh**, we performed thermogravimetric analysis (TGA), differential scanning calorimetry (DSC) and polarizing optical microscopy (POM); the obtained results are shown in Fig. 1 and Fig. S1 (ESI†). POM images were captured by sandwiching the samples between two glass substrates. All of the images were taken upon cooling after heating to the isotropic phase. As shown in Fig. 1a, all the synthesized compounds display excellent thermal stability as indicated by their decomposition temperature (T_d, temperature with 5% weight loss) over 200 °C. Compared to **AntPh**, **AntPh-OC8** and **AntPh-C8** manifest enhanced thermal stability due to the introduction of alkoxy and alkyl chains. Particularly, alkoxy substituted compound **AntPh-OC8** exhibits the highest decomposition temperature (T_d = 281 °C) among the synthesized materials. These experimental results indicate that optoelectronic devices based on **AntPh-OC8** and **AntPh-C8** will potentially possess better thermal stability at high processing temperatures than that of non-substituted compound **AntPh**. As can be seen in Fig. 1b, two exothermic peaks are observed in the DSC curves of **AntPh-OC8** and **AntPh-C8** during both the cooling and heating processes, while only one exothermic peak is found in the case of the non-substituted compound **AntPh**. For **AntPh-OC8**, during the cooling process, the first exothermic peak at 185.4 °C is associated with an isotropic-to-sematic X (Sm-X) transition with a large enthalpy of 132.19 J g^{-1}. The second exothermic peak at 110.6 °C corresponds

to a transition from the Sm-X phase to the crystal phase with a smaller enthalpy of 9.99 J g^{-1}. Furthermore, it is evident that the textures shown in Sm-X are nearly the same as for the crystal phase apart from the appearance of more cracks between adjacent grains according to the POM images (Fig. S1a and b, ESI†). These observations suggest that Sm-X is a highly ordered liquid crystal phase. Also, **AntPh-C8** shows similar liquid crystal properties to **AntPh-OC8**; however, **AntPh** does not exhibit liquid crystal characteristics due to the appearance of only one exothermic peak in the DSC curve, in both the cooling and heating processes. We conclude that highly ordered semiconductor films of **AntPh-OC8** and **AntPh-C8** can be obtained by preparing or annealing the thin films in a temperature range of the liquid crystal phase, which would enable the development of high-performance semiconductor devices.

Electrochemical, optical absorption and fluorescence properties

UV-vis and cyclic voltammetry (CV) were conducted to study the electronic properties of **AntPh-C8**, **AntPh-OC8** and **AntPh**. The highest occupied molecular orbital (HOMO) energy level is estimated from the onset of the oxidation potential. Since the reduction potential is not accessible in CV, the lowest unoccupied molecular orbital (LUMO) energy is assessed by adding the optical gap to the HOMO energy. The UV-vis absorption and electrochemical properties of these three compounds are summarized in Table 1. As shown in Fig. 2a, the UV-vis absorption
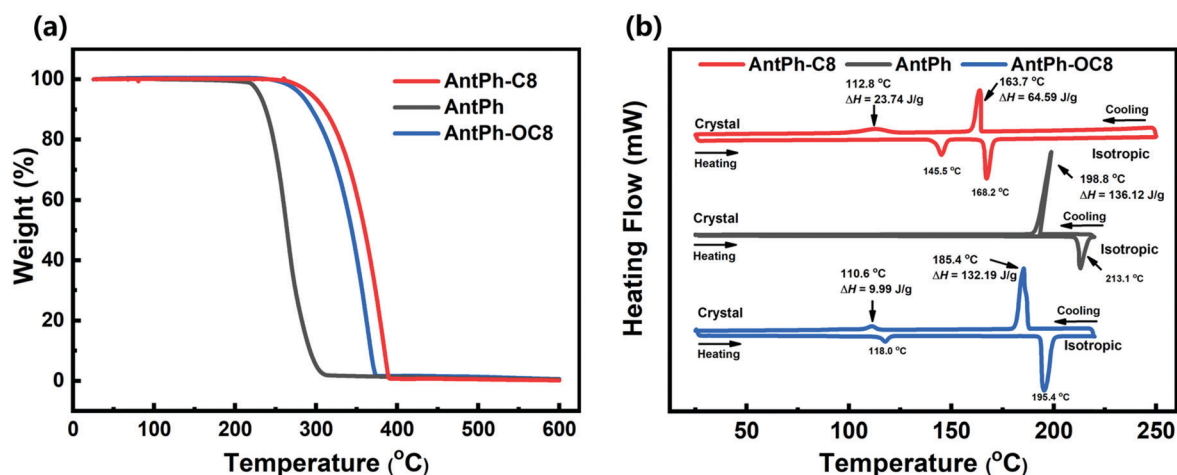

Fig. 1 TGA (a) and DSC (b) curves of **AntPh-OC8**, **AntPh-C8** and **AntPh**.

Table 1 UV-vis absorption and electrochemical properties of **AntPh-OC8**, **AntPh-C8** and **AntPh**

	λ_{onset}^{abs} (nm)		λ_{max}^{abs} (nm)		E_g^{e} (eV)	E_{ox} (V)	E_{HOMO}^{f} (eV)	E_{LUMO}^{g} (eV)
	Solution[a]	Thin film[b]	Solution[c]	Thin film[d]				
AntPh	399	429	350, 368, 388	412, 388, 367	2.89	0.84	−5.37	−2.48
AntPh-C8	402	428	350, 368, 390	413, 389, 368	2.90	0.90	−5.43	−2.53
AntPh-OC8	407	430	352, 370, 390	414, 390, 368	2.88	0.76	−5.29	−2.41

Notes: [a] Absorption onset wavelength of CH$_2$Cl$_2$ solution. [b] Absorption onset wavelength of thin films. [c] Absorption peak wavelength of CH$_2$Cl$_2$ solution. [d] Absorption peak wavelength of thin films. [e] Optical gap calculated from the absorption onset wavelength of thin films: $E_g = 1240/\lambda_{onset}$. [f] Calculated from the oxidative potential of CV: $E_{HOMO} = -[E_{ox} - E_{(Fc/Fc^+)} + 4.8]$ (eV). [g] $E_{LUMO} = (E_{HOMO} + E_g)$ (eV).
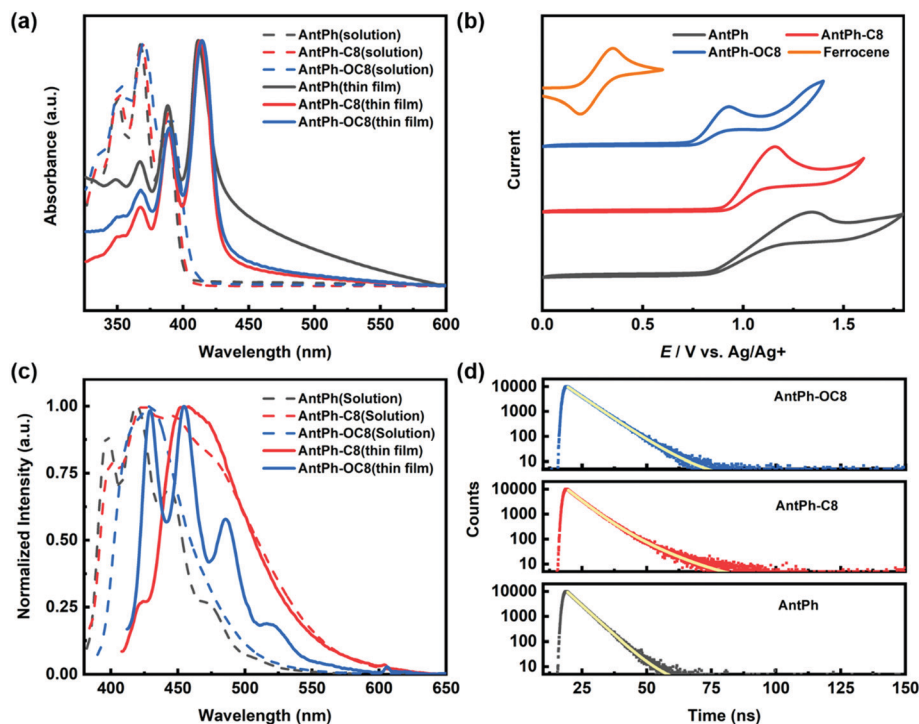
Fig. 2 UV-vis absorption spectra (a), cyclic voltammograms (b), photoluminescence spectra (c) and transient fluorescence spectra (d) of **AntPh**, **AntPh-C8** and **AntPh-OC8** in dilute CH_2Cl_2 solution and thin films. The scanning rate of the CV measurements is 0.5 V s^{-1}.

spectra of these materials exhibit the vibrational fine structure of typical anthracene derivatives. Also, bathochromic shifts are observed in the thin films compared with the curves in CH_2Cl_2 solution. Additionally, the relative intensity of the 0–0 peak in thin films is stronger than that of the 0–1 and 0–2 peaks, while the strongest absorption peak in solution belongs to the 0–1 transition. Therefore, a J-aggregation packing motif, which is advantageous for the suppression of fluorescence quenching, in thin films of **AntPh**, **AntPh-C8** and **AntPh-OC8** can be deduced from the spectral signatures.[43] The maximum absorption edges of the thin films based on **AntPh**, **AntPh-C8** and **AntPh-OC8** are at around 429, 428 and 430 nm, respectively, from which their corresponding energy gaps are determined to be 2.89, 2.90 and 2.88 eV. The electronic states were investigated by CV to understand the charge injection process and the stability of **AntPh-C8**, **AntPh-OC8** and **AntPh**. The redox properties of these three compounds are shown in Fig. 2b. The HOMO levels of **AntPh**, **AntPh-C8** and **AntPh-OC8** are determined to be −5.37, −5.43 and −5.29 eV, respectively, while their corresponding LUMO levels are calculated to be −2.48, −2.53 and −2.41 eV. A deep HOMO level is desirable for good air stability. In addition, the introduction of an alkoxy chain to the conjugated anthracene skeleton elevates the HOMO level of **AntPh-OC8** from −5.37 eV to −5.29 eV likely due to the electron-donating property of the attached oxygen atom. The HOMO level of **AntPh-OC8** (−5.29 eV) is better matched with the work function of gold (5.2 eV) than that of the other two materials, which indicates that higher mobility and lower V_{th} could be obtained in OFETs based on **AntPh-OC8**. The photoluminescence spectra of these

three compounds are revealed in Fig. 2c. Compared with the UV-vis spectrum of **AntPh-OC8**, the vibrational structure of the corresponding fluorescence spectrum in CH_2Cl_2 solution is blurred to some extent. The vibrational fine structure vanishes while an integrated fluorescence peak appears at 429 nm. For **AntPh-C8**, the intensity of the 0–2 and 0–3 transitions is increased and a shoulder-like peak with nearly the same intensity as the strongest 0–1 peak is located between 446 and 500 nm. In addition, the full width at half maximum (FWHM) of 100 nm in the case of **AntPh-OC8** is twice that of **AntPh**. The featureless bands with little vibrational structure of the **AntPh-OC8** and **AntPh-C8** fluorescence spectra are attributed to a stronger interaction between organic molecules and the surrounding solvent molecular "cage", as the side chains will change the polarity of the two organic molecules. In contrast to the spectrum in CH_2Cl_2 solution, the vibrational structure characteristic was reproduced in the fluorescence spectrum of **AntPh-OC8** in a thin film, which illustrates that the aggregation of **AntPh-OC8** molecules has little impact on the fluorescence properties of **AntPh-OC8** thin films. However, the featureless fluorescence spectrum of **AntPh-C8** implies more intense interaction in **AntPh-C8** thin films, probably resulting from closer π–π stacking. Table 2 summarizes the fluorescence parameters of these compounds.

The PLQYs of **AntPh-OC8**, **AntPh-C8** and **AntPh** in degassed CH_2Cl_2 solution are measured to be 40.9%, 37.6% and 23.3%, respectively. The introduction of side chains to the 2-phenyl-anthracene core increased the fluorescence efficiency of the anthracene derivatives. Transient decay profiles of **AntPh-OC8**, **AntPh-C8** and **AntPh** were investigated in degassed CH_2Cl_2 solution.

Table 2 Fluorescence properties of **AntPh-OC8**, **AntPh-C8** and **AntPh**

	$\lambda^{PL}_{MAX}{}^{a}$ (nm)		Φ^{b} (PLQY)		τ (ns) (lifetime in solution)	$k_r{}^c$ (ns^{-1}) (radiative decay rate)	$k_{nr}{}^d$ (ns^{-1}) (nonradiative decay rate)
	Solution	Thin film	Solution	Thin film			
AntPh	397, 419, 443	—	23.3%	—	4.67	0.050	0.165
AntPh-C8	400, 425, 446	422, 455	37.6%	5.1%	6.13	0.061	0.101
AntPh-OC8	429	429, 455, 485	40.9%	12.5%	6.40	0.064	0.092

Notes: [a] Fluorescence emission peak wavelength of CH_2Cl_2 solution and thin films at room temperature. [b] Photoluminescence quantum yield measured in CH_2Cl_2 solution and thin films at room temperature. [c] Calculated according to the equation: $k_r = \Phi/\tau$. [d] Calculated according to the equation: $k_r/k_{nr} = \Phi/(1 - \Phi)$.

The prompt lifetimes of **AntPh-OC8**, **AntPh-C8** and **AntPh** are 6.40 ns, 6.13 ns and 4.67 ns, respectively. According to the equation $k_r = \Phi/\tau$, the corresponding radiative decay rates of **AntPh-OC8**, **AntPh-C8** and **AntPh** are calculated to be 0.064 ns^{-1}, 0.061 ns^{-1} and 0.050 ns^{-1}, respectively. The increased radiation rates of anthracene derivatives substituted by side chains partly result from the introduction of an electron-donating group (alkyl chain and alkoxy chain). The simulation results (Fig. S2, ESI†) indicate that there is a hyperconjugation effect between the conjugated **AntPh** core and side chains, which contributes to the narrowed band gap and consequently to the increased k_r.[44] In addition, the nonradiative decay rates of **AntPh-OC8** and **AntPh-C8** are suppressed significantly, which may be ascribed to the suppression of intersystem crossing caused by a stabilized singlet state.[45] The PLQYs of **AntPh-OC8** and **AntPh-C8** in thin film form are determined to be 12% and 5%, respectively, which are reasonable due to the exciton quenching arising from surface defects commonly observed in films.[23,46] The solid-state emission of the three compounds is further characterized in powder form by POM with a mercury lamp as the excitation source (Fig. S3, ESI†). The experimental results show that the alkoxy chain substituted compounds exhibit higher fluorescence yield, revealing their potential for applications in luminescent devices. The transient fluorescence spectra of **AntPh**, **AntPh-C8** and **AntPh-OC8** are shown in Fig. 2d.

Charge transport properties

OFETs were fabricated in a top-contact, bottom-gate configuration by vacuum-deposition to explore the charge transport properties of **AntPh-OC8**, **AntPh-C8** and **AntPh**. Various substrate temperatures and thermal annealing temperatures were chosen to obtain the optimal device performance. The annealing temperature is selected according to the temperature range of the liquid crystal phase, as observed in DSC. The performance characteristics of

the devices, including the mobility (μ), threshold voltage (V_{th}), and the on/off current ratio (I_{on}/I_{off}) measured in air, are summarized in Table 3. Typical transfer and output characteristics are shown in Fig. 3. As expected, the OFET based on **AntPh** does not exhibit significant semiconductor device performance due to the poor morphology of the corresponding thin film. The possible reason for the poor morphology is that **AntPh** possesses a lower sublimation temperature, which leads to re-evaporation of the semiconductor film and cracks appear in the semiconductor film during the evaporation process of gold electrodes. The **AntPh-OC8** and **AntPh-C8**-based OFETs exhibit p-type charge transport. Moreover, the obtained results suggest that the OFET performance strongly depends on the substrate and thermal annealing temperatures.

As demonstrated in Table 3 and Fig. 3a, the mobility of the OFET based on **AntPh-C8** fabricated at room temperature (T_{sub} = 25 °C) is as high as 1.05 cm^2 V^{-1} s^{-1} and 0.92 ± 0.10 cm^2 V^{-1} s^{-1} on average. When the substrate temperature is elevated from 25 to 80 °C, the average mobility is slightly improved from 0.92 to 1.22 cm^2 V^{-1} s^{-1}. Meanwhile, V_{th} increases dramatically from 32.8 to 41.9 V. In other words, the OFETs fabricated at 80 °C (T_{sub} = 80 °C) actually exhibit inferior performance though with a higher mobility.[47] Unfortunately, the OFET mobility degrades to 0.19 ± 0.04 cm^2 V^{-1} s^{-1} after annealing at 130 °C for 5 min. A possible reason is that the damaged film morphology with more cracks affects the effective transport of charge carriers as the devices are annealed at 130 °C. Interestingly, though the mobility of the OFET based on **AntPh-OC8** fabricated at room temperature (T_{sub} = 25 °C) is only 0.23 ± 0.05 cm^2 V^{-1} s^{-1}, the maximum mobility is up to 2.59 cm^2 V^{-1} s^{-1} when the substrate temperature is increased to 80 °C (T_{sub} = 80 °C), and the threshold voltage is not obviously changed. In contrast to **AntPh-C8**, the enhanced mobility of the OFET based on **AntPh-OC8** can be attributed to the higher

Table 3 Selected parameters of OFETs based on **AntPh-OC8** and **AntPh-C8**

	AntPh-C8			AntPh-OC8		
	$\mu_{sat}{}^a$ [cm^2 V^{-1} s^{-1}]	I_{on}/I_{off}	V_{th} [V]	$\mu_{sat}{}^a$ [cm^2 V^{-1} s^{-1}]	I_{on}/I_{off}	V_{th} [V]
T_{sub} = 25 °C^b	0.92 ± 0.10(1.05)	>1.0 × 10^6	−32.8 ± 1.9	0.23 ± 0.05(0.33)	>1.0 × 10^6	−32.1 ± 1.5
T_{sub} = 80 °C^c	1.22 ± 0.14(1.56)	>1.0 × 10^6	−41.9 ± 2.7	2.30 ± 0.16(2.59)	>1.0 × 10^7	−34.5 ± 0.9
T_{PA} = 130 °C^d	0.19 ± 0.04(0.27)	>1.0 × 10^5	−40.9 ± 1.4	0.87 ± 0.13(1.01)	>1.0 × 10^7	−27.6 ± 1.7

Notes: [a] Average values in the saturation regime are extracted from more than 8 devices, the values inside the parenthesis indicate the maximum mobility under various fabrication conditions. [b] thin films deposited on the substrate at room temperature. [c] thin films deposited on the substrate at 80 °C. [d] devices annealed at 130 °C for 5 min after the deposition of gold electrodes.
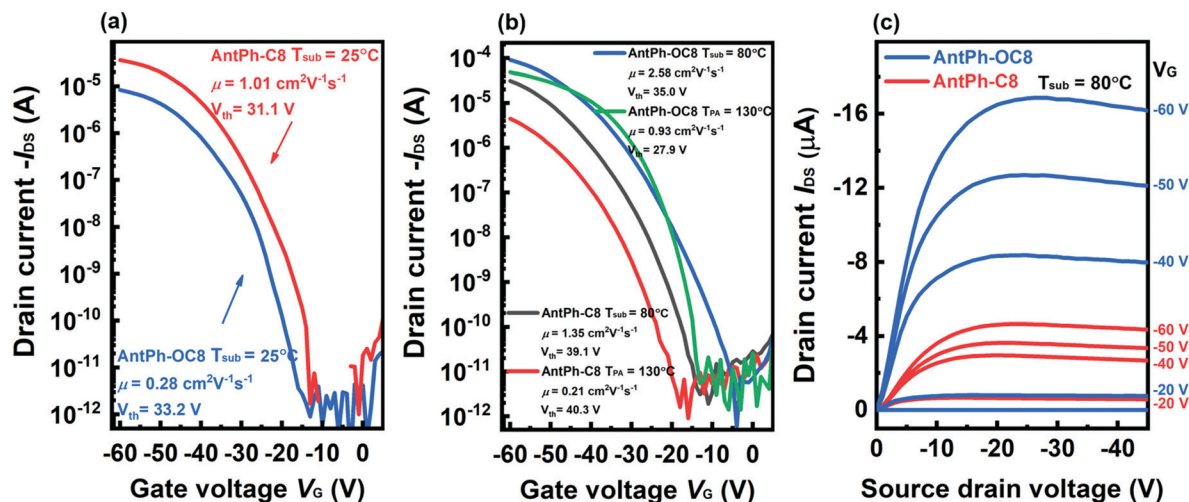
Fig. 3 OFET characteristics of **AntPh-C8** and **AntPh-OC8**: (a) transfer curve (I_d–V_g characteristics) of the OFET fabricated at T_{sub} = 25 °C and (b) transfer curve of the OFET fabricated at T_{sub} = 80 °C and T_{PA} = 130 °C and (c) output curve (I_d–V_d characteristics) at T_{sub} = 80 °C.

on-state drain current (I_d) but not the increase of the threshold voltage. Simultaneously, the mobility of the OFET is further improved up to 0.87 ± 0.13 cm^2 V^{-1} s^{-1} after thermal annealing in the temperature range of the Sm X phase (130 °C). The mobility of the best device reaches 1.01 cm^2 V^{-1} s^{-1}, and I_{on}/I_{off} is over 10^7. The performance comparison between various fabrication conditions indicates that the thin film annealed at 130 °C and deposited at 80 °C is less defective and fully relaxed compared to the as-fabricated counterpart. All these results confirm that liquid crystalline **AntPh-OC8** is an excellent candidate for application in organic electronics.

Film morphology analysis

X-ray diffraction (XRD) and atomic force microscopy (AFM) are effective characterization methods to gain insight into the variations of OFET performance under various device fabrication conditions. The XRD results of **AntPh-OC8** and **AntPh-C8** thin films fabricated on octyl trichlorosilane (OTS) modified substrates are depicted in Fig. 4. As for the thin films of **AntPh-OC8** deposited at T_{sub} = 25 °C, the first diffraction peak is located at 4.0° from which a d-spacing of 2.19 nm is figured out according to Bragg's law. The molecular length of **AntPh-OC8** is 2.40 nm based on the

Fig. 4 XRD patterns of **AntPh-OC8** (a) and **AntPh-C8** (b) thin films prepared on OTS modified SiO$_2$/Si substrates at the various temperature conditions.

modeling results using Gaussian09 (Fig. S6, ESI†). The experimental results elucidate that the molecules of **AntPh-OC8** adopt a nearly edge-on orientation on the substrate which coincides with the charge transport direction. After annealing at 130 °C, the appearance of higher-order diffraction peaks and the increased relative intensity of the second diffraction peak suggest enhanced crystallinity over a longer range of the **AntPh-OC8** thin film. Moreover, it is noteworthy that a third reflection peak appears at 9.6°. Hence, it is reasonable to suppose that there would be a peak located at 1.9° corresponding to a d-spacing of 4.64 nm which should be assigned to the first-order reflection peak. Evidently, the occurrence of a phase transition from monolayer to bilayer structure is in accordance with the results from AFM combined with DSC thermograms. Likewise, perpendicular molecular alignment is adopted in **AntPh-C8** polycrystalline thin films and the second peak appearing at 5.9° after annealing demonstrates a similar phase transition for **AntPh-C8**.

As shown in Fig. 5, AFM images reveal the temperature dependence of the thin film morphology. For thin films of **AntPh-OC8** deposited at T_{sub} = 25 °C, obvious island-like grains with terrace structures can be observed in Fig. 5a. This phenomenon suggests that thin films are deposited on the substrate in a layer-by-layer fashion. Limited grain size and poor connectivity between the crystalline grains lead to inferior device performance of **AntPh-OC8** under this condition. After annealing at 130 °C, thin films containing larger grains, which are well-connected to each other, contribute to the enhanced charge transport. When **AntPh-OC8** is deposited at T_{sub} = 80 °C, larger domains (with a diameter of ∼500 nm) are obtained. Meanwhile, the boundaries of thin films between the crystalline grains became narrower. The experiment results suggest that OFETs based on such thin films will have higher mobility. As predicted, the highest mobility of 2.59 cm^2 V^{-1} s^{-1} is achieved under this condition. It is noteworthy that terrace structures were maintained under various thin film fabrication conditions. The cross-sectional profiles along the sky-blue arrow in Fig. 5d indicate the step height of the terrace to be around
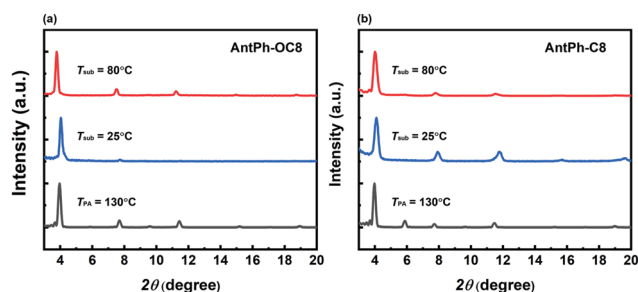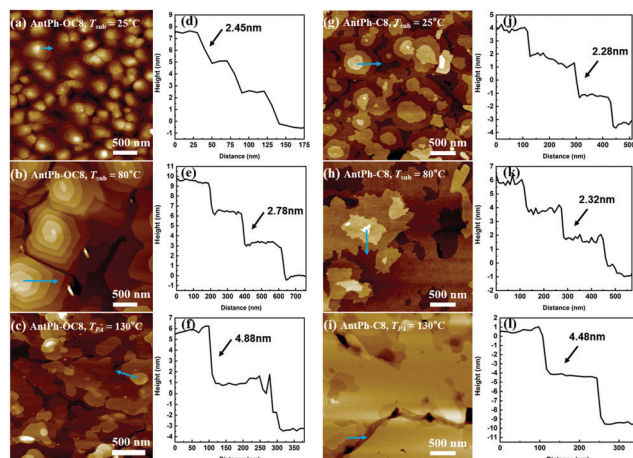

Table 4 Electroluminescence (EL) performance of OLEDs based on **AntPh-OC8**

Material	V_{on} (V)	CE (cd A^{-1})		PE (lm W^{-1})		CIE (x,y)@ 100 cd m^{-2}
		Max	@100 cd m^{-2}	Max	@100 cd m^{-2}	
AntPh-OC8	5.2	1.86	1.82	0.81	0.75	(0.176, 0.108)

Fig. 8 Electroluminescence characteristics of the OLED based on **AntPh-OC8**. (a) Current density (left axis) and luminance (right axis) versus bias voltage. (b) Current efficiency (left axis) and power efficiency (right axis) versus luminance. (c) EL spectra of the OLED under different bias voltages. (d) CIE chromaticity diagram of the resulting OLED.

as a hole transport layer (HTL). N,N-bis[4-(dibenzofuran-4-yl)phenyl]-p-terphenyl-4-amine (TPN-DBF) is employed as the electron-blocking layer (EBL). On the other side, Liq is used as the electron-injection layer and ANT-BIZ (1-(4-(10-([1,1′-biphenyl]-4-yl)anthracen-9-yl)phenyl)-2-ethyl-1H-benzo[d]imidazole) is incorporated as the electron transport layer (ETL). It is noteworthy that non-doped devices were fabricated at first but the OLEDs degraded under bias stress so that characterization of the non-doped devices was not accessible. The degradation of non-doped devices may be attributed to the oxidation of accumulated excited **AntPh-OC8** molecules in the emitting layer (EML). Then, we considered a host-dopant EML to avoid excessive hot excitons. 9-(Naphthalen-1-yl)-10-(4-(naphthalen-2-yl)phenyl)anthracene (BH) is chosen as the matrix material for **AntPh-OC8** in the emitting layer (EML) with a doping ratio of 1:13 (**AntPh-OC8**:Host). The electroluminescence (EL) properties of the doped devices are listed in Table 4 and detailed OLED characteristics are shown in Fig. 8. The maximum CE of 1.82 cd A^{-1} is obtained with blue emission peaking at 436 nm and the fabricated device showed CIE coordinates of (0.176, 0.108). Considering that the radiative singlet exciton generation efficiency is 25% for fluorescent molecules in OLEDs, though with a CE of 1.82 cd A^{-1}, **AntPh-OC8** is a promising pure-blue emitter.

Conclusion

In conclusion, we report two liquid crystal materials, **AntPh-OC8** and **AntPh-C8**, based on an anthracene conjugated core.

Compared with their parent molecule **AntPh**, both of the newly synthesized materials, which are simply obtained by the introduction of side chains, exhibited enhanced fluorescence and superior charge transport properties. The improvement of the PLQY from 23.3% to 40.9% is attributed to the increased radiative decay rates and inhibition of nonradiative decay. Both of the materials showed a smooth morphology and compact packing motif, which is beneficial for effective charge transport. The temperature dependence of the thin film morphology and resulting OFET performance was also investigated to shed light on the thermal behavior of the two liquid crystal materials. In addition, we presented successful demonstration of OPTs and OLEDs based on **AntPh-OC8** and **AntPh-C8**, revealing the potential application of our newly developed materials in multifunctional devices. Our work proposes a simple strategy for the development of multifunctional LC materials to simultaneously boost the charge-carrier mobility and fluorescence efficiency. We anticipate that our newly developed materials could be competitive alternatives for multifunctional devices, especially for OLETs or photodetectors.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

References

1 Q. Zhang, D. F. Perepichka and Z. Bao, Fred Wudl's fifty-year contribution to organic semiconductors, *J. Mater. Chem. C*, 2018, **6**, 3483–3484.

2 C. Wang, H. Dong, W. Hu, Y. Liu and D. Zhu, Semiconducting pi-conjugated systems in field-effect transistors: a material odyssey of organic electronics, *Chem. Rev.*, 2012, **112**, 2208–2267.

3 H. Sirringhaus, 25th anniversary article: organic field-effect transistors: the path beyond amorphous silicon, *Adv. Mater.*, 2014, **26**, 1319–1335.

4 P.-Y. Gu, Z. Wang, G. Liu, H. Yao, Z. Wang, Y. Li, J. Zhu, S. Li and Q. Zhang, Synthesis, Full Characterization, and Field Effect Transistor Behavior of a Stable Pyrene-Fused N-Heteroacene with Twelve Linearly Annulated Six-Membered Rings, *Chem. Mater.*, 2017, **29**, 4172–4175.

5 P.-Y. Gu, J. Zhang, G. Long, Z. Wang and Q. Zhang, Solution-processable thiadiazoloquinoxaline-based donor–acceptor

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Mater. Chem. Front., 2020, **4**, 3546–3555 | **3553**

small molecules for thin-film transistors, *J. Mater. Chem. C*, 2016, **4**, 3809–3814.

6 P. Y. Gu, Y. Zhao, J. H. He, J. Zhang, C. Wang, Q. F. Xu, J. M. Lu, X. W. Sun and Q. Zhang, Synthesis, physical properties, and light-emitting diode performance of phenazine-based derivatives with three, five, and nine fused six-membered rings, *J. Org. Chem.*, 2015, **80**, 3030–3035.

7 N. Johnson and A. Chiang, Highly photosensitive transistors in single-crystal silicon thin films on fused silica, *Appl. Phys. Lett.*, 1984, **45**, 1102–1104.

8 K. J. Baeg, M. Binda, D. Natali, M. Caironi and Y. Y. Noh, Organic light detectors: photodiodes and phototransistors, *Adv. Mater.*, 2013, **25**, 4267–4295.

9 C. F. Liu, X. Liu, W. Y. Lai and W. Huang, Organic Light-Emitting Field-Effect Transistors: Device Geometries and Fabrication Techniques, *Adv. Mater.*, 2018, **30**, e1802466.

10 C. Zhang, P. Chen and W. Hu, Organic Light-Emitting Transistors: Materials, Device Configurations, and Operations, *Small*, 2016, **12**, 1252–1294.

11 G. Zhao, H. Dong, Q. Liao, J. Jiang, Y. Luo, H. Fu and W. Hu, Organic field-effect optical waveguides, *Nat. Commun.*, 2018, **9**, 4790.

12 X. Gong, Organic field-effect optical waveguides: a new break-through all organic optoelectronics, *Sci. China: Chem.*, 2018, **62**, 293–294.

13 P. Audebert and F. Miomandre, Electrofluorochromism: from molecular systems to set-up and display, *Chem. Sci.*, 2013, **4**, 575–584.

14 J. Sun and Z. Liang, Swift Electrofluorochromism of Donor-Acceptor Conjugated Polytriphenylamines, *ACS Appl. Mater. Interfaces*, 2016, **8**, 18301–18308.

15 M. Chen, L. Yan, Y. Zhao, I. Murtaza, H. Meng and W. Huang, Anthracene-based semiconductors for organic field-effect transistors, *J. Mater. Chem. C*, 2018, **6**, 7416–7444.

16 J. Zhao, Z. Chi, Z. Yang, Z. Mao, Y. Zhang, E. Ubba and Z. Chi, Recent progress in the mechanofluorochromism of distyrylanthracene derivatives with aggregation-induced emission, *Mater. Chem. Front.*, 2018, **2**, 1595–1608.

17 J. Zhang, S. Ma, H. Fang, B. Xu, H. Sun, I. Chan and W. Tian, Insights into the origin of aggregation enhanced emission of 9,10-distyrylanthracene derivatives, *Mater. Chem. Front.*, 2017, **1**, 1422–1429.

18 M. Pope, H. Kallmann and P. Magnante, Electroluminescence in organic crystals, *J. Chem. Phys.*, 1963, **38**, 2042–2043.

19 H. Meng, F. Sun, M. B. Goldfinger, G. D. Jaycox, Z. Li, W. J. Marshall and G. S. Blackman, High-performance, stable organic thin-film field-effect transistors based on bis-5′-alkylthiophen-2′-yl-2,6-anthracene semiconductors, *J. Am. Chem. Soc.*, 2005, **127**, 2406–2407.

20 H. Meng, F. Sun, M. B. Goldfinger, F. Gao, D. J. Londono, W. J. Marshal, G. S. Blackman, K. D. Dobbs and D. E. Keys, 2,6-Bis[2-(4-pentylphenyl) vinyl] anthracene: a stable and high charge mobility organic semiconductor with densely packed crystal structure, *J. Am. Chem. Soc.*, 2006, **128**, 9304–9305.

21 H. Klauk, U. Zschieschang, R. T. Weitz, H. Meng, F. Sun, G. Nunes, D. E. Keys, C. R. Fincher and Z. Xiang, Organic Transistors Based on Di(phenylvinyl)anthracene: Performance and Stability, *Adv. Mater.*, 2007, **19**, 3882–3887.

22 K. Ito, T. Suzuki, Y. Sakamoto, D. Kubota, Y. Inoue, F. Sato and S. Tokito, Oligo(2,6-anthrylene)s: Acene–Oligomer Approach for Organic Field-Effect Transistors, *Angew. Chem., Int. Ed.*, 2003, **42**, 1159–1162.

23 A. Dadvand, A. G. Moiseev, K. Sawabe, W. H. Sun, B. Djukic, I. Chung, T. Takenobu, F. Rosei and D. F. Perepichka, Maximizing field-effect mobility and solid-state luminescence in organic semiconductors, *Angew. Chem., Int. Ed.*, 2012, **51**, 3837–3841.

24 J. Li, K. Zhou, J. Liu, Y. Zhen, L. Liu, J. Zhang, H. Dong, X. Zhang, L. Jiang and W. Hu, Aromatic extension at 2, 6-positions of anthracene toward an elegant strategy for organic semiconductors with efficient charge transport and strong solid state emission, *J. Am. Chem. Soc.*, 2017, **139**, 17261–17264.

25 J. Liu, H. Zhang, H. Dong, L. Meng, L. Jiang, L. Jiang, Y. Wang, J. Yu, Y. Sun, W. Hu and A. J. Heeger, High mobility emissive organic semiconductor, *Nat. Commun.*, 2015, **6**, 10032.

26 Z. Qin, H. Gao, J. Liu, K. Zhou, J. Li, Y. Dang, L. Huang, H. Deng, X. Zhang, H. Dong and W. Hu, High-Efficiency Single-Component Organic Light-Emitting Transistors, *Adv. Mater.*, 2019, **31**, e1903175.

27 X. Zhang, H. Dong and W. Hu, Organic Semiconductor Single Crystals for Electronics and Photonics, *Adv. Mater.*, 2018, **30**, e1801048.

28 H. Iino and J. Hanna, Availability of liquid crystallinity in solution processing for polycrystalline thin films, *Adv. Mater.*, 2011, **23**, 1748–1751.

29 T. Izawa, E. Miyazaki and K. Takimiya, Solution-processible organic semiconductors based on selenophene-containing heteroarenes, 2,7-dialkyl[1] benzoselenopheno [3,2-*b*][1] benzoselenophenes (C n-BSBSs): syntheses, properties, molecular arrangements, and field-effect transistor characteristics, *Chem. Mater.*, 2009, **21**, 903–912.

30 M. J. Han, D. Wei, Y. H. Kim, H. Ahn, T. J. Shin, N. A. Clark, D. M. Walba and D. K. Yoon, Highly Oriented Liquid Crystal Semiconductor for Organic Field-Effect Transistors, *ACS Cent. Sci.*, 2018, **4**, 1495–1502.

31 Y. He, M. Sezen, D. Zhang, A. Li, L. Yan, H. Yu, C. He, O. Goto, Y.-L. Loo and H. Meng, High Performance OTFTs Fabricated Using a Calamitic Liquid Crystalline Material of 2-(4-Dodecyl phenyl)[1]benzothieno[3,2-*b*][1]benzothiophene, *Adv. Electron. Mater.*, 2016, **2**, 1600179.

32 H. Iino, T. Usui and J. Hanna, Liquid crystals for organic thin-film transistors, *Nat. Commun.*, 2015, **6**, 6828.

33 T. Kato, M. Yoshio, T. Ichikawa, B. Soberats, H. Ohno and M. Funahashi, Transport of ions and electrons in nano-structured liquid crystals, *Nat. Rev. Mater.*, 2017, **2**, 1–20.

34 M. Chen, Y. Zhao, L. Yan, S. Yang, Y. Zhu, I. Murtaza, G. He, H. Meng and W. Huang, A Unique Blend of 2-Fluorenyl-2-anthracene and 2-Anthryl-2-anthracene Showing White Emission and High Charge Mobility, *Angew. Chem., Int. Ed.*, 2017, **56**, 722–727.

35 L. Yan, Y. Zhao, H. Yu, Z. Hu, Y. He, A. Li, O. Goto, C. Yan, T. Chen, R. Chen, Y.-L. Loo, D. F. Perepichka, H. Meng and

W. Huang, Influence of heteroatoms on the charge mobility of anthracene derivatives, *J. Mater. Chem. C*, 2016, **4**, 3517–3522.

36 A. Li, L. Yan, M. Liu, I. Murtaza, C. He, D. Zhang, Y. He and H. Meng, Highly responsive phototransistors based on 2,6-bis(4-methoxyphenyl)anthracene single crystal, *J. Mater. Chem. C*, 2017, **5**, 5304–5309.

37 A. Li, L. Yan, C. He, Y. Zhu, D. Zhang, I. Murtaza, H. Meng and O. Goto, In-plane isotropic charge transport characteristics of single-crystal FETs with high mobility based on 2,6-bis(4-methoxyphenyl)anthracene: experimental cum theoretical assessment, *J. Mater. Chem. C*, 2017, **5**, 370–375.

38 Y. Chen, C. Li, X. Xu, M. Liu, Y. He, I. Murtaza, D. Zhang, C. Yao, Y. Wang and H. Meng, Thermal and Optical Modulation of the Carrier Mobility in OTFTs Based on an Azo-anthracene Liquid Crystal Organic Semiconductor, *ACS Appl. Mater. Interfaces*, 2017, **9**, 7305–7314.

39 C. Xu, P. He, J. Liu, A. Cui, H. Dong, Y. Zhen, W. Chen and W. Hu, A General Method for Growing Two-Dimensional Crystals of Organic Semiconductors by ''Solution Epitaxy'', *Angew. Chem., Int. Ed.*, 2016, **55**, 9519–9523.

40 Y. Xu, L. Ren, D. Dang, Y. Zhi, X. Wang and L. Meng, A Strategy of ''Self-Isolated Enhanced Emission'' to Achieve Highly Emissive Dual-State Emission for Organic Luminescent Materials, *Chem. – Eur. J.*, 2018, **24**, 10383–10389.

41 Y. S. Yang, T. Yasuda, H. Kakizoe, H. Mieno, H. Kino, Y. Tateyama and C. Adachi, High performance organic field-effect transistors based on single-crystal microribbons and microsheets of solution-processed dithieno[3,2-*b*:2′,3′-*d*]thiophene derivatives, *Chem. Commun.*, 2013, **49**, 6483–6485.

42 S. Ito, M. Wehmeier, J. D. Brand, C. Kübel, R. Epsch, J. P. Rabe and K. Müllen, Synthesis and self-assembly of functionalized hexa-peri-hexabenzocoronenes, *Chem. – Eur. J.*, 2000, **6**, 4327–4342.

43 F. C. Spano, The spectral signatures of Frenkel polarons in H-and J-aggregates, *Acc. Chem. Res.*, 2009, **43**, 429–439.

44 Y. Niko, S. Kawauchi, S. Otsu, K. Tokumaru and G. Konishi, Fluorescence enhancement of pyrene chromophores induced by alkyl groups through sigma-pi conjugation: systematic synthesis of primary, secondary, and tertiary alkylated pyrenes at the 1, 3, 6, and 8 positions and their photophysical properties, *J. Org. Chem.*, 2013, **78**, 3196–3207.

45 N. Nijegorodov, V. Vasilenko, P. Monowe and M. Masale, Systematic investigation of the influence of methyl groups upon fluorescence parameters and the intersystem crossing rate constant of aromatic molecules, *Spectrochim. Acta, Part A*, 2009, **74**, 188–194.

46 R. Katoh, K. Suzuki, A. Furube, M. Kotani and K. Tokumaru, Fluorescence Quantum Yield of Aromatic Hydrocarbon Crystals, *J. Phys. Chem. C*, 2009, **113**, 2961–2965.

47 H. H. Choi, K. Cho, C. D. Frisbie, H. Sirringhaus and V. Podzorov, Critical assessment of charge mobility extraction in FETs, *Nat. Mater.*, 2017, **17**, 2–7.

48 Y. Mizuki and H. Ito, *US Pat.*, 20180323377A1, 2014.

49 T. Hirose, H. Kadoma, S. Shitagaki and S. Seo, *US Pat.*, 20180076394A1, 2014.